

## Dr. Susanne Lachenmann

Chairwoman of the general works council,  
Infineon Technologies AG



Member of the Infineon Technologies  
Supervisory Board since 2015  
(elected until 2025)

### Personal information

Year of birth 1967  
Residence Ravensburg  
Nationality German

### Education

1995 PhD in Natural Science (Dr. rer. nat.), Eberhard-Karls-University Tübingen  
1993 Diploma in physics, Eberhard-Karls-University Tübingen

### Professional career

Since 2024 Chairwoman of the general works council, Infineon Technologies AG  
Since 2020 Principal Engineer, Infineon Technologies AG  
Since 2008 Lead Development Engineer for Design Enabling & Services, Infineon Technologies AG  
Design methodology, physical verification (Principal Parasitic Extraction Methodology)  
2005 – 2008 Development Engineer, Qimonda AG  
Design for KERF and test chips  
1999 – 2005 Development Engineer for memory products, Infineon Technologies AG  
Various design divisions: KERF and test chips, embedded DRAM;  
Design methodology, technology package development  
1998 – 1999 Development Engineer for memory products, Siemens AG  
Design methodology, technology package development  
1995 – 1998 Research assistant at the Institute of Thin Film and Ion Technology, Research Center Jülich

### Memberships in other statutory supervisory boards in Germany

None

**Memberships in comparable supervisory bodies of business enterprises in Germany and abroad**

None

